





**Preliminary data** 

#### **General description** 1.

The PCF87852 combines the Bluetooth™ protocol stack, Link Controller (LC), Link Manager (LM), and Host Controller Interface (HCI) firmware of the Bluetooth system specification in a single IC with embedded software. Together with an RF module, a few external components and an antenna it forms a Bluetooth system. In most cases this module will be attached to a host, for example a GSM baseband controller or a PC processor. The PCF87852 may also be used for embedded Bluetooth applications by running the upper software layers also from the on-chip memory. Together with an external voice codec a Bluetooth headset application can be realized.

The industry standard ARM7TDMI™ microcontroller with low power consumption is integrated together with ROM memory and SRAM. There are no provisions for external controllers to directly access on-chip data memory. Communication with an external host, for example a PC, GSM or PDA, is handled via the HCI.

Industry standard interfaces such as I<sup>2</sup>C-bus<sup>™</sup>, PCM and IOM<sup>®</sup> are supported by on-chip hardware. Additionally, a UART interface is available that can be used as the Bluetooth host controller interface.

The Bluetooth controller consists of a number of functional blocks that operate under control of the embedded microcontroller. The microcontroller has access to these blocks via the AMBA System Bus (ASB) and the VLSI Peripheral Bus (VPB).

The PCF87852 is designed to be used together with an RF IC as low-cost, low-power, radio-based cable replacement or wireless link. This link will be the basis for PCs, telephones, PDAs and peripherals to communicate together on an ad-hoc basis. It will replace cables and enables a wireless personal network.

The PCF87852 is especially suited for applications without the need for analog voice input or output, e.g. cellular telephones or computing platforms.

#### 2. Features

#### 2.1 Baseband hardware

- Embedded ARM7TDMI microprocessor
- 224 kbytes ROM memory
- 38 kbytes SRAM memory
- 8 kbytes internal data RAM (IRAM) for Bluetooth controller
- Watchdog timer
- Two 32-bit system timers



#### **Bluetooth baseband controller**

- Bluetooth controller including scrambling, CRC generation and checking, FEC encoding and decoding and ciphering according the "Specification of the Bluetooth System, Version 1.1"
- Bluetooth connections supporting:
  - Maximum 3 active connections (ACL)
  - One voice connection (SCO).
- CVSD transcoder
- RF interface
- RSSI measurement
- On-chip 1.8 V voltage regulator
- 8-bit D/A and A/D conversion for various purposes; e.g. PA control
- Power-on reset
- System clock crystal oscillator
- Low-power crystal oscillator for a low-frequency clock input
- System clock request signal for control of external clock source
- Microprocessor interfaces including UART, I<sup>2</sup>C-bus, combined PCM/IOM and general purpose I/O-pins
- Patch mechanism for code updates and corrections.

#### 2.2 Firmware

- Interface drivers
- Bluetooth controller driver
- Link Controller (LC)
- Link Manager (LM)
- Host Controller Interface (HCI)
- L2CAP, RFCOMM and SDP
- Small profiles and application software (i.e Bluetooth headset).

#### 2.3 General

- Core and interface supply: 1.8 V; RF interface supply: 2.7 V to 3.4 V
- Operating temperature range: –40 °C to +85 °C
- Package: LFBGA73 ( $7 \times 7 \text{ mm}^2$  and 0.5 mm pitch).

#### 3. Applications

- Cell phones and smart phones
- Computing applications (PC, notebook and PDA)
- Cellular accessories (Bluetooth headsets).

**Bluetooth baseband controller** 

## 4. Quick reference data

Table 1:	Quick reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Supplies							
V <sub>SS</sub>	ground voltage		[1]	-	0	-	V
V <sub>DDCO1</sub>	first core supply voltage		[2]	1.65	1.8	1.95	V
V <sub>DDCO2</sub>	second core supply voltage		[2]	1.65	1.8	1.95	V
V <sub>DDIORF</sub>	RF interface supply voltage		[2][3][4]	1.65	3.0	3.6	V
V <sub>DDIO18</sub>	1.8 V I/O supply voltage		[2]	1.65	1.8	1.95	V
V <sub>DDIOV</sub>	variable I/O supply voltage		[2]	1.65	3.0	3.6	V
V <sub>DDA</sub>	analog supply voltage		[2]	1.65	1.8	1.95	V
V <sub>DDO</sub>	oscillator supply voltage		[2][5]	1.65	1.8	1.95	V
Power co	nsumption <sup>[6]</sup>						
I <sub>DD(on)</sub>	operating supply current for an active ACL link and continuous DM1 and DH1 mode	$I_{DD} = I_{DDC} + I_{DDA};$ ARM active; $V_{DDC} = V_{DDA} = 1.8 V$		-	13	-	mA
I <sub>DDIORF(tx)</sub>	RF interface supply current in transmit mode	$V_{DDIORF} = 3.0 V$		-	125	-	μΑ
I <sub>DD(lp)</sub>	low-power supply current in low power mode	$I_{DD} = I_{DDC} + I_{DDA}$ ; ARM off; DCXO off; LPO on (32.768 kHz)		-	40	-	μA
I <sub>DD(off)</sub>	off mode supply current for lowest possible current	$I_{DD} = I_{DDC} + I_{DDA}$ ; ARM off; clocks off	[7]	-	30	-	μΑ
Digital I/O	pins						
I/O pins at	VDDIORF						
VIH	HIGH-level input voltage			2.0	-	V <sub>DDIORF</sub>	V
VIL	LOW-level input voltage			0	-	0.8	V
V <sub>OH</sub>	HIGH-level output voltage	I <sub>OH</sub> = 4 mA		$V_{\text{DDIORF}}-0.4$	-	-	V
V <sub>OL</sub>	LOW-level output voltage	I <sub>OL</sub> = 4 mA		-	-	0.4	V
I/O pins at	V <sub>DDIO18</sub>						
V <sub>IH</sub>	HIGH-level input voltage			0.7V <sub>DDIO18</sub>	-	V <sub>DDIO18</sub>	V
V <sub>IL</sub>	LOW-level input voltage			0	-	0.3V <sub>DDIO18</sub>	V
V <sub>hys</sub>	hysteresis voltage			-	0.3V <sub>DDIO18</sub>	-	V
V <sub>OH</sub>	HIGH-level output voltage	I <sub>OH</sub> = 4 mA		$V_{DDIO18}-0.4$	-	-	V
V <sub>OL</sub>	LOW-level output voltage	I <sub>OL</sub> = 4 mA		-	-	0.4	V
I/O pins at	V <sub>DDIOV</sub>						
V <sub>IH</sub>	HIGH-level input voltage			$0.7V_{DDIOV}$	-	V <sub>DDIOV</sub>	V
V <sub>IL</sub>	LOW-level input voltage			0	-	0.3V <sub>DDIOV</sub>	V
V <sub>hys</sub>	hysteresis voltage			-	0.3V <sub>DDIOV</sub>	-	V
V <sub>OH</sub>	HIGH-level output voltage	I <sub>OH</sub> = 3 mA		$V_{DDIOV} - 0.4$	-	-	V
V <sub>OL</sub>	LOW-level output voltage	I <sub>OL</sub> = 3 mA				0.4	V

[2] It must be insured that the supply rise on each of the supply pins from 0 V to 1.1 V is shorter than 5 ms.

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- [3]  $V_{DDIORF}$  is only tested at 2.7 V to 3.4 V.
- $[4] V_{DDIORF} = V_{DDIOV.}$
- [5] I<sup>2</sup>C-bus is only functional for voltages between 3.0 V and 3.6 V.

Table 2:

- [6] The power consumptions are very dependent on the software settings and can vary a lot.
- [7] CMOS leakage current. All blocks are disabled except the bias currents of the band gap reference and the power-on reset circuit.

BGB101 radio module				
Symbol <sup>[1]</sup>		Domain	Тур	Unit
SCO and HV3 packet	[2]	1.80 V	13.0	mA
		2.85 V	12.0	mA
		total P	57.6	mW
ACL, DM1 or DH1 packets and bidirectional data	[2]	1.80 P	12.6	mA
		2.85 V	10.0	mA
		total P	51.2	mW
ACL, DM5 or DH5 packet transmit and NULL packet	[2]	1.80 V	12.6	mA
receive		2.85 V	26.0	mA
		total P	96.8	mW
ACL, DM5 or DH5 packet receive and NULL packet	[2]	1.80 V	12.6	mA
transmit		2.85 V	32.0	mA
		total P	113.9	mW
ACL, sniff mode and external 32 kHz (T <sub>sniff</sub> = 500 ms)	ns) [3]	1.80 V	0.32	mA
		2.85 V	0.40	mA
		total P	1.71	mW
ACL, sniff mode and internal 32 kHz ( $T_{sniff} = 500 \text{ ms}$ )	[4]	1.80 V	0.65	mA
		2.85 V	0.40	mA
		total P	2.31	mW
Low power page/inquiry scan and external 32 kHz	[3]	1.80 V	0.23	mA
		2.85 V	0.42	mA
		total P	1.61	mW
Low power page/inquiry scan and internal 32 kHz	[4]	1.80 V	0.55	mA
		2.85 V	0.42	mA
		total P	2.19	mW

Typical power consumption figures of the PCF87852 in combination with

[1] All measurements performed on sampling basis with HCI firmware loaded in the PCF87852 internal ROM.

[2] Measurements are done with the 13 MHz oscillator in slave mode.

[3] Measurements are done with a 32.768 kHz crystal connected to generate the Bluetooth low power clock.

[4] Measurements are done with a 13 MHz crystal connected and the Bluetooth low power clock derived from the 13 MHz.

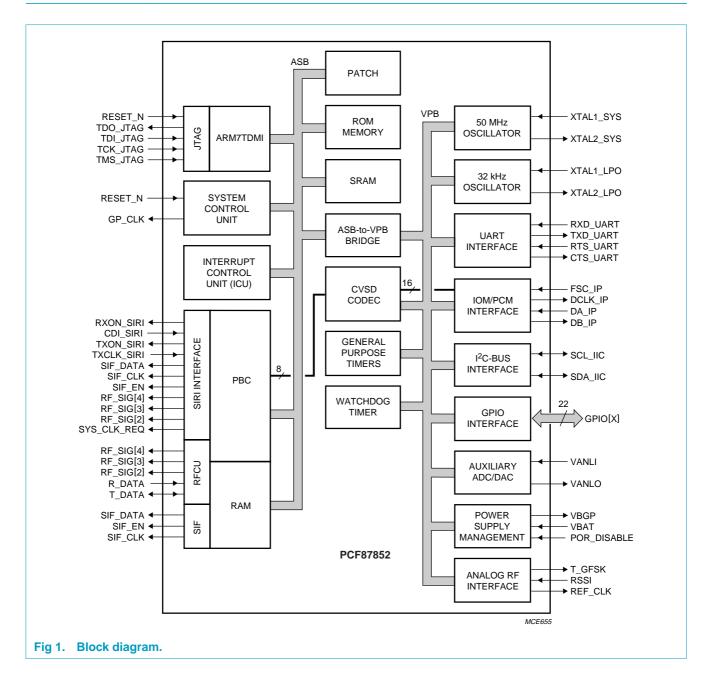
## 5. Ordering information

Table 3: Ordering information							
Type number	Package	Package					
	Name	Description	Version				
PCF87852E	LFBGA73	plastic low profile fine-pitch ball grid array package; 73 balls; body $7 \times 7 \times 1.05$ mm	SOT751-1				

#### 9397 750 12161 Preliminary data

**Bluetooth baseband controller** 

### 6. Block diagram



### 7. Functional description

The PCF87852 is designed to be used as a low-cost, low-power radio-based cable replacement, or wireless link. This link will be the basis for PCs, telephones, PDAs headsets and peripherals to communicate together on an ad-hoc basis. It is designed to handle the Bluetooth specification.

The PCF87852 is intended to combine the Bluetooth protocol stack, link controller, link manager, HCI Firmware and radio of the Bluetooth system specification in one IC with embedded software. Figure 2 shows a typical example of the PCF87852 in its environment. Together with few external components and an antenna it forms a Bluetooth system. In most cases this system will be attached to a host, for example a GSM baseband controller or a PC processor.

The industry standard ARM7TDMI microcontroller with low power consumption per MHz is integrated. There is a ROM memory and a static RAM on-chip. There are no provisions for external controllers to directly access on-chip data memories. Communication with an external host, for example a PC, GSM or PDA, is handled via the HCI.

The PCF87852 is able to run the complete Bluetooth application up to HCI.

A number of industry standard interfaces such as IOM/PCM, I<sup>2</sup>C-bus, and UART are supported by on-chip hardware to act as possible host interfaces.

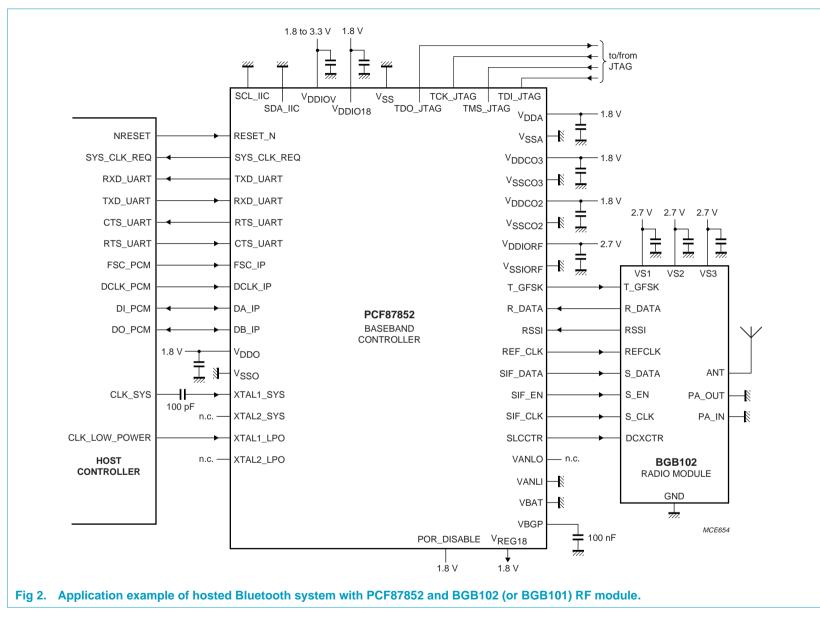
The Bluetooth link controller consists of a number of functional blocks that operate under control of the embedded microcontroller. The microcontroller has access to these blocks via the AMBA System Bus (ASB) and VLSI Peripheral Bus (VPB).

Figure 1 shows the various blocks and their interconnections.



**Rev. 01** 23 April 2004

8 of 12



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**Bluetooth baseband controller** 

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**CF87852** 

#### **Bluetooth baseband controller**

## 8. Limiting values

Table 4:Limiting valuesIn accordance with the Absolute Maximum Rating System (IEC 60134).						
Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>DDC</sub>	core supply voltage			-0.5	+2.5	V
V <sub>DDIORF</sub>	RF interface supply voltage			-0.5	+4.6	V
V <sub>DDIO18</sub>	1.8 V I/O supply voltage			-0.5	+2.5	V
V <sub>DDIOV</sub>	variable I/O supply voltage			-0.5	+4.6	V
V <sub>DDA</sub>	analog supply voltage			-0.5	+2.5	V
V <sub>DDO</sub>	oscillator supply voltage			-0.5	+2.5	V
VI	input voltage on any pin	with respect to ground (V <sub>SS</sub> )	[1]	-0.5	V <sub>DDX</sub> + 0.5	V
l <sub>l</sub>	input DC current through any pin			-	100	mA
P <sub>tot</sub>	total power dissipation			-	200	mW
T <sub>amb</sub>	ambient temperature			-40	+85	°C
T <sub>stg</sub>	storage temperature			-40	+125	°C

[1]  $V_{DDX}$  represents the supply voltage of the functional block associated with the pin.



## 9. Revision history

Table 5: Revision history			
Rev	Date	CPCN	Description
01	20040423	-	Preliminary data (9397 750 12161)

#### **Bluetooth baseband controller**

### **10. Data sheet status**

Level	Data sheet status <sup>[1]</sup>	Product status <sup>[2][3]</sup>	Definition
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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[3] For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

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**Short-form specification** — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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